The RF Line NPN Silicon RF Power Transistor

Designed for 12.5 Volt UHF large–signal amplifier applications in industrial and commercial FM equipment operating to 512 MHz.

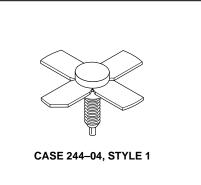
- Specified 12.5 Volt, 512 MHz Characteristics
 - Output Power = 10 W Gain = 8.0 dB (Typ) Efficiency = 65% (Typ)
- Gold Metallized, Emitter Ballasted for Long Life and Reliability
- Capable of 20:1 VSWR Load Mismatch at 16 V Supply Voltage
- Circuit board photomaster available upon request by contacting RF Tactical Marketing in Phoenix, AZ.

MAXIMUM RATINGS

Rating	Symbol	Value	Unit	
Collector-Emitter Voltage	VCEO	16.5	Vdc	
Collector-Base Voltage	VCBO	38	Vdc	
Emitter–Base Voltage	VEBO	4.0	Vdc	
Collector Current — Continuous	IC	2.75	Adc	
Total Device Dissipation @ T _A = 25°C Derate above 25°C	PD	44 0.25	Watts W/°C	
Storage Temperature Range	T _{stg}	-65 to +150	°C	
Operating Junction Temperature	Тj	200	°C	



MRF653



THERMAL CHARACTERISTICS

Characteristic	Symbol	Мах	Unit
Thermal Resistance, Junction to Case	R _{θJC}	4.0	°C/W

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS				•	•
Collector–Emitter Breakdown Voltage ($I_C = 20 \text{ mAdc}, I_B = 0$)	V(BR)CEO	16.5	—	_	Vdc
Collector–Emitter Breakdown Voltage ($I_C = 20 \text{ mAdc}, V_{BE} = 0$)	V(BR)CES	38	—	_	Vdc
Emitter–Base Breakdown Voltage ($I_E = 5.0 \text{ mAdc}, I_C = 0$)	V(BR)EBO	4.0	—	_	Vdc
Collector Cutoff Current (V_{CE} = 15 Vdc, V_{BE} = 0)	ICES	_	—	5.0	mAdc
ON CHARACTERISTICS	•				
DC Current Gain (I _C = 1.0 Adc, V _{CE} = 5.0 Vdc)	hFE	20	—	120	—
DYNAMIC CHARACTERISTICS					
Output Capacitance (V_{CB} = 12.5 Vdc, I_E = 0, f = 1.0 MHz)	C _{ob}		22	28	pF
FUNCTIONAL TESTS	•		•		
Common–Emitter Amplifier Power Gain (V _{CC} = 12.5 Vdc, P _{out} = 10 W, f = 512 MHz)	G _{pe}	7.0	8.0	-	dB
Collector Efficiency (V _{CC} = 12.5 Vdc, P _{out} = 10 W, f = 512 MHz)	ης	55	65	-	%
Load Mismatch Stress (V _{CC} = 16 Vdc, f = 512 MHz, P _{in} (1) = 2.6 W, VSWR = 20:1, All Phase Angles)	ψ	No Degradation in Output Power			

NOTE:

1. P_{in} = 2.0 dB over the typical input power required for 10 W output power @ 12.5 Vdc.







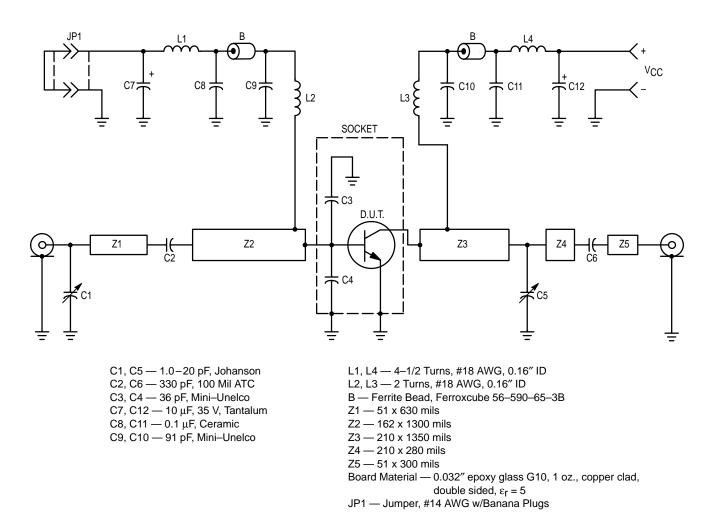


Figure 1. Broadband Test Circuit Schematic

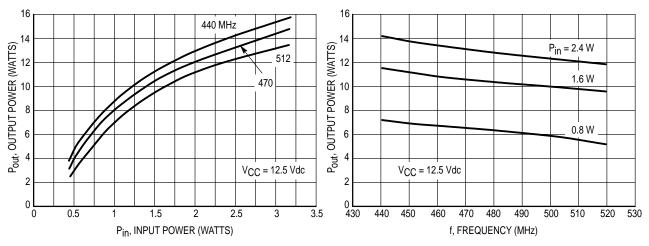


Figure 2. Output Power versus Input Power

Figure 3. Output Power versus Frequency

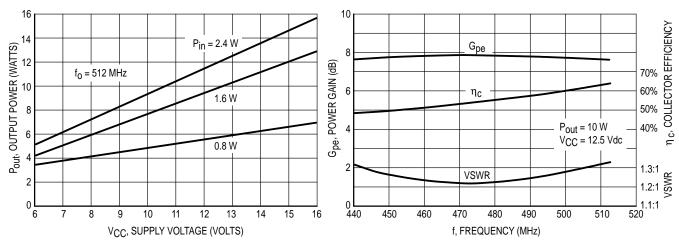


Figure 4. Output Power versus Supply Voltage

Figure 5. Typical Broadband Circuit Performance

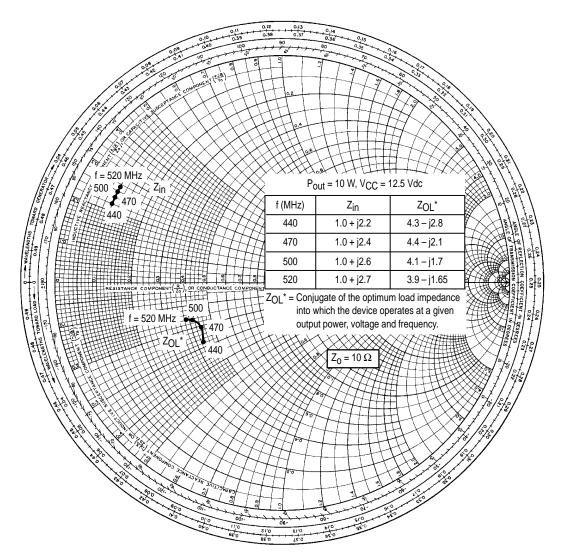
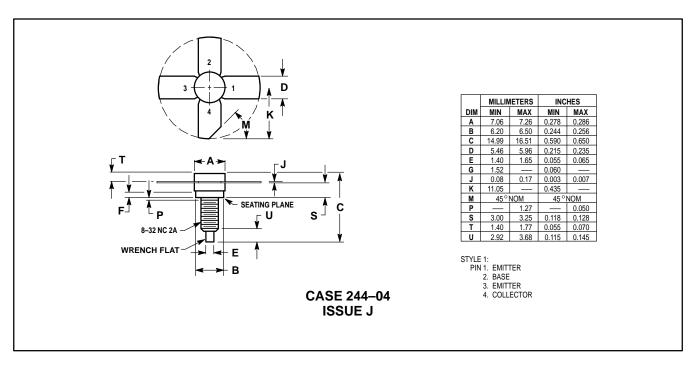


Figure 6. Series Equivalent Input and Output Impedance

PACKAGE DIMENSIONS



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ASIA/PACIFIC: Motorola Semiconductors H.K. Ltd.; 8B Tai Ping Industrial Park, 51 Ting Kok Road, Tai Po, N.T., Hong Kong. 852–26629298

JAPAN: Nippon Motorola Ltd.: SPD, Strategic Planning Office, 4-32-1,

Nishi-Gotanda, Shinagawa-ku, Tokyo 141, Japan. 81-3-5487-8488

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